



100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

3.3 A

Features

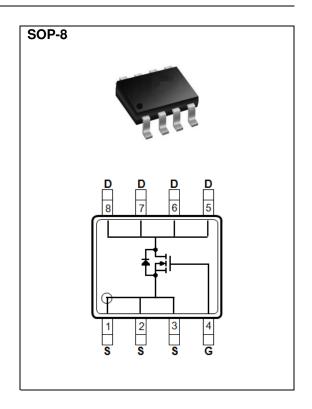
- RDS(ON), VGS@10V, ID@3.3A<115mΩ
- RDS(ON), VGS@4.5V, ID@1.5A<120mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

• Case: SOP-8 package

• Terminals: Solderable per MIL-STD-750, Method 2026

Marking: L9452A



$\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A = 25 ^{\circ} \text{C unless otherwise noted})$

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	100	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		3.3	А	
	T _A =70°C	I _D	2.6		
Pulsed Drain Current (Note 1)		I _{DM}	13.2	Α	
Power Dissipation	T _A =25°C		2.5		
	T _A =70°C	P_{D}	1.6	W	
Single Pulse Avalanche Energy (Note 5)		E _{AS}	3.2	mJ	
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C	
Typical Thermal resistance - Junction to Ambient, $t \le 10s^{(Note 5)}$		R _{eJA}	50	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_D =250uA	100	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1.0	1.76	2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =3.3A	-	92	115	mΩ		
		V _{GS} =4.5V,I _D =1.5A	-	95	120			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\underline{+}20V, V_{DS}=0V$	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_g	V_{DS} =50V, I_{D} =2A, V_{GS} =10V (Note 1,2)	-	20	-	nC		
Gate-Source Charge	Q_gs		-	3.2	-			
Gate-Drain Charge	Q_{gd}		-	3.6	-			
Input Capacitance	Ciss		-	1413	-	pF		
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, f =1.0MHZ	-	60	-			
Reverse Transfer Capacitance	Crss		-	34	-			
Turn-On Delay Time	td _(on)	$\begin{array}{c} V_{DD}{=}50V,\ I_{D}{=}1A,\\ V_{GS}{=}10V,\\ R_{G}{=}3.3\Omega \end{array}$	-	18	-	ns		
Turn-On Rise Time	tr		-	4.3	-			
Turn-Off Delay Time	td _(off)		-	41	-			
Turn-Off Fall Time	tf		-	4.2	-			
Drain-Source Diode								
Maximum Continuous Drain-Source				-	3.3	Α		
Diode Forward Current	I _S		_					
Diode Forward Voltage	$V_{\mathtt{SD}}$	I _S =1.0A, V _{GS} =0V	-	0.73	1.0	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ=25°C.
- 4. The maximum current rating is package limited.
- 5. The test condition is L=0.1mH, I_{AS} =8A, V_{DD} =25V, V_{GS} =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

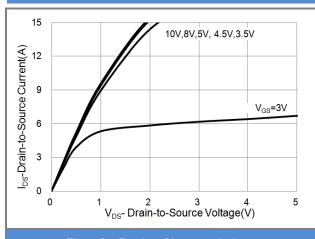


Fig.1 On-Region Characteristics

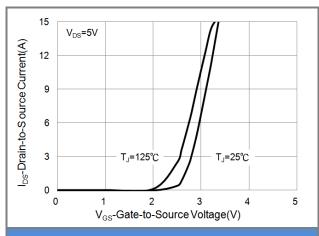


Fig.2 Transfer Characteristics

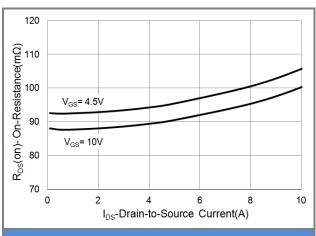


Fig.3 On-Resistance vs. Drain Current

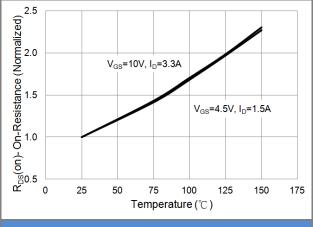


Fig.4 On-Resistance vs. Junction temperature

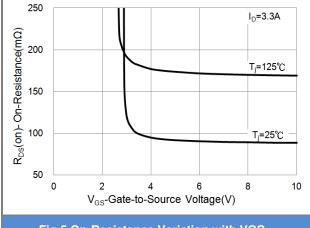


Fig.5 On-Resistance Variation with VGS.

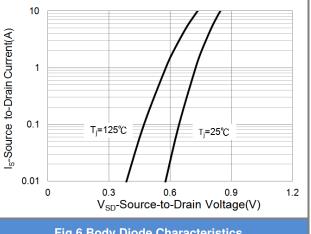


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

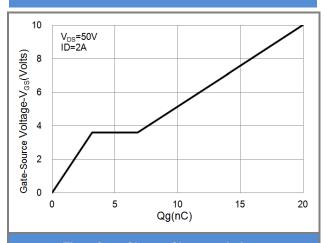


Fig.7 Gate-Charge Characteristics

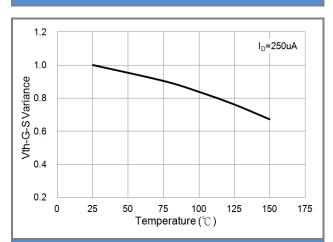
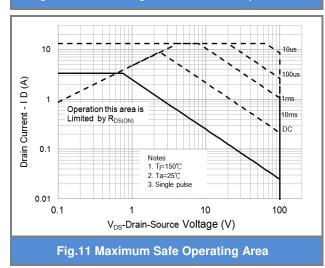


Fig.9 Threshold Voltage Variation with Temperature.



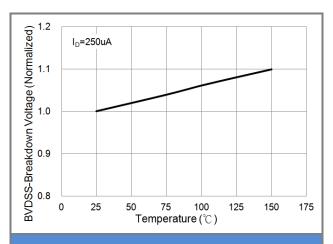


Fig.8 Breakdown Voltage Variation vs. Temperature

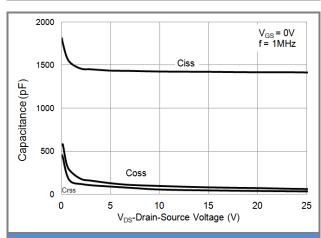


Fig.10 Capacitance vs. Drain-Source Voltage.





TYPICAL CHARACTERISTIC CURVES

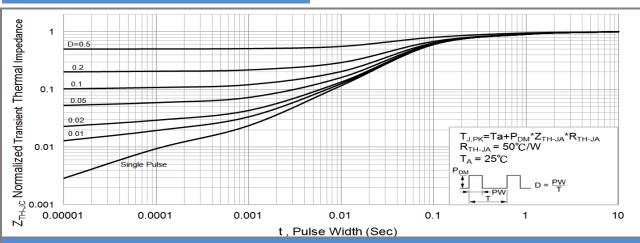


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

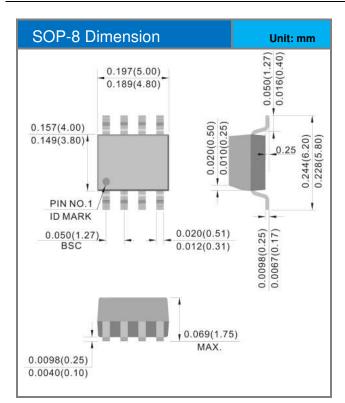


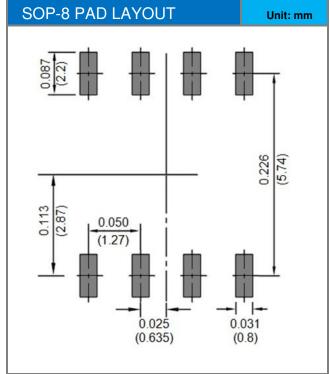


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9452A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9452A	Halogen free

Packaging Information & Mounting Pad Layout









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